

PATENT NUMBER and ISSUE DATE

	APPL NUM 10054438	FILING DATE 01/22/2002	CLASS 428	SUBCLASS	GAU 1775	3	exam N F	iner amm	γ		
Ī	*APPLICANTS: U'ren Gregory;										
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	**CONTINUING DATA VERIFIED: THIS APPLICATION IS A DIV OF 09/667,274 09/22/2000 PAT 6,365,479										
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	** FOREIGN APPLICATIONS VERIFIED:										
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-	TITLE: Method for independent control of polycrystalline silicon-germanium in a silicon-germanium HBT and related structure U.S.DEPT. OF COMM.PAT. 8 TM-PTO-436L(Rev. 12-94)										
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		Assistant Examiner	Total Claims		Print Claim for O.G				
ISSUE FEE			DRAWING						
Amount Due	Date Paid	1	Sheets Drwg.	Figs.Drwg.	Print Fig.				
		Primary Examiner		dir.					
TERMINAL		PREPARED FOR ISSUE	Application Examiner						
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